

E课网集成电路培训课程系列之

AHB-SoC芯片架构 -AHB-SRAMC

讲师: K.Lin

课程目标

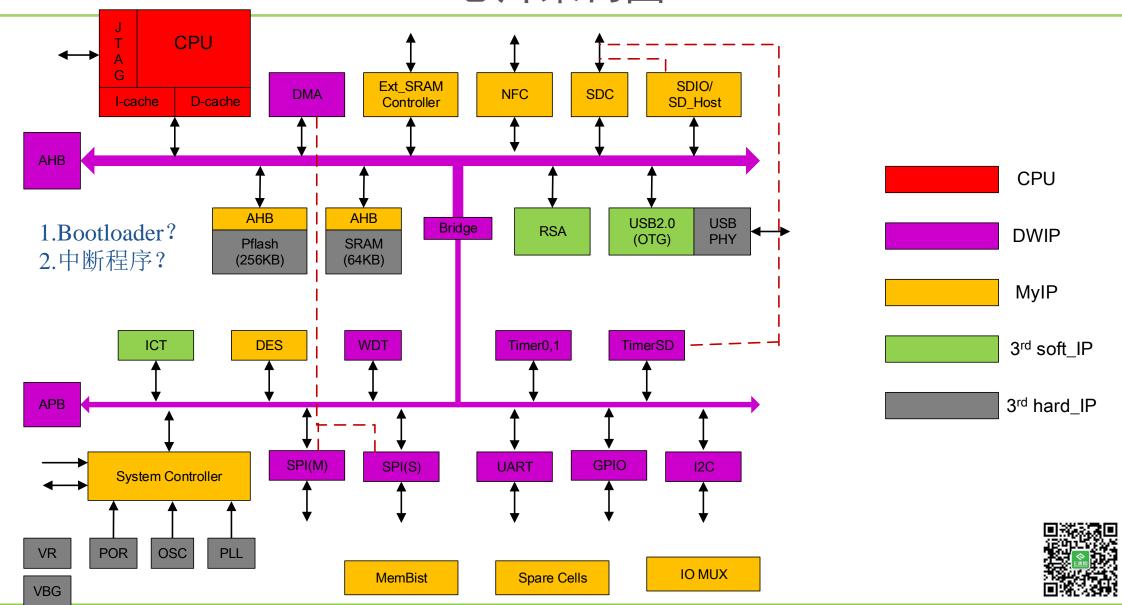


- 1. 掌握AHB-SoC芯片架构
- 2. 掌握片上内存控制器AHB-SRAMC的主要作用
- 3. 熟悉AHB-SRAMC的设计架构
- 4. 熟悉AHB slave接口的基本功能
- 5. 熟悉SRAM memory的接口时序



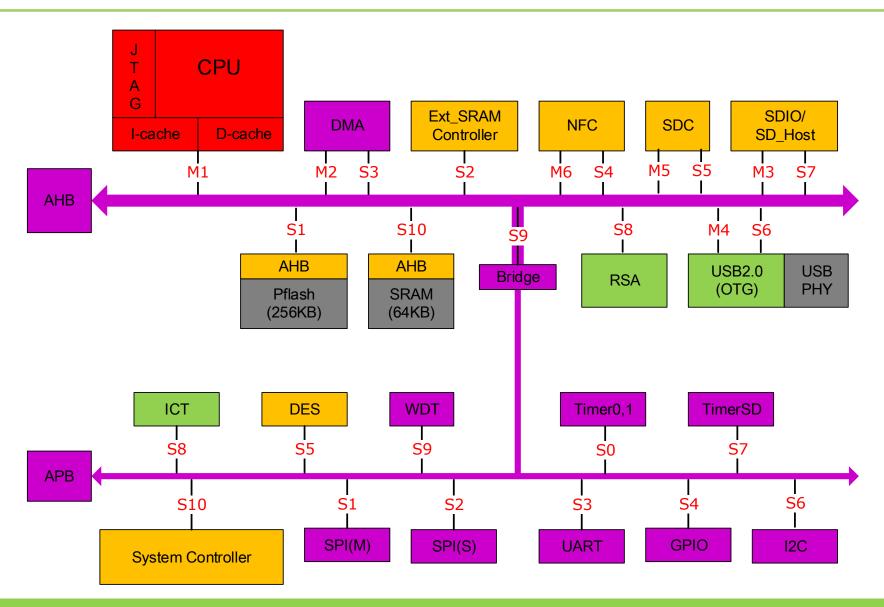
AHB-SoC芯片架构图 - IP





AHB-SoC芯片架构图 - Master & Slave

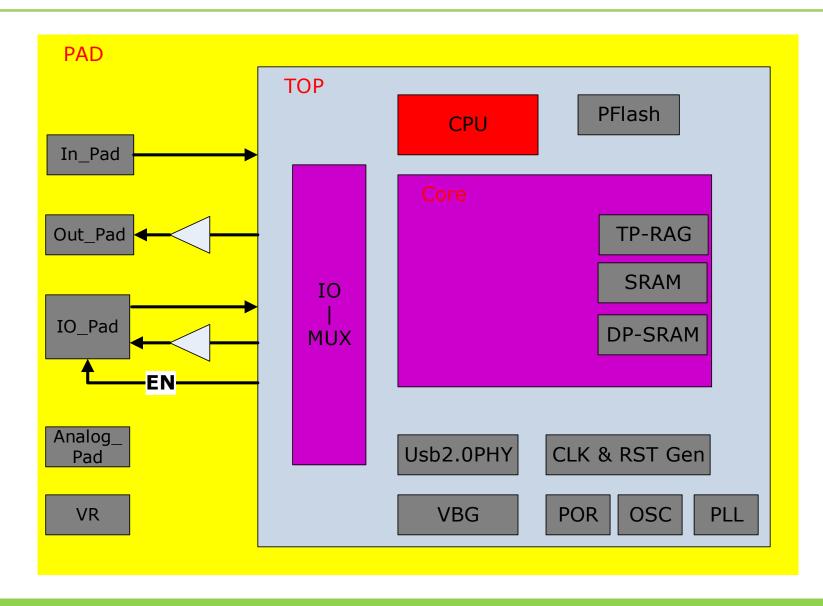






AHB-SoC芯片架构图 - PAD

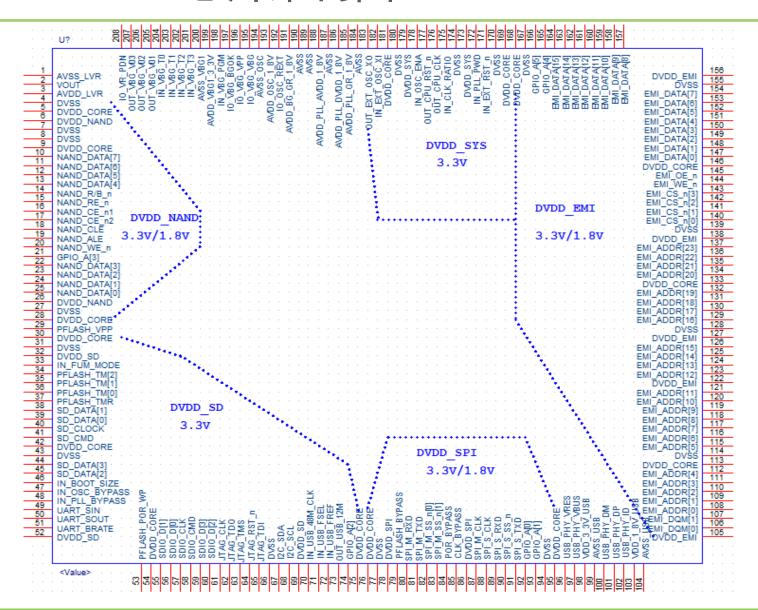






AHB-SoC芯片架构图 - Power & Pin

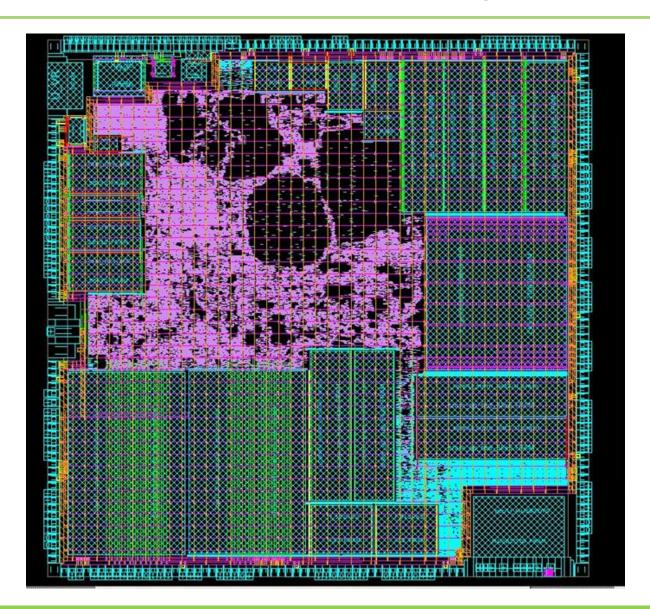






AHB-SoC芯片架构图 - Layout 版图

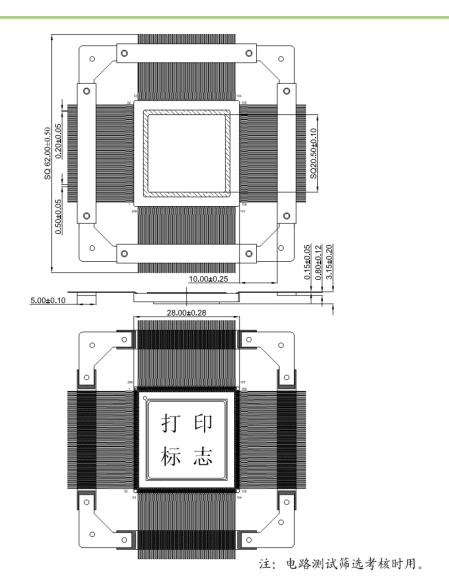






AHB-SoC芯片架构图 - Package





印

32.60±0.30

注: 封装过程中不使用该图, 仅在电路测试筛选考核完成后用。



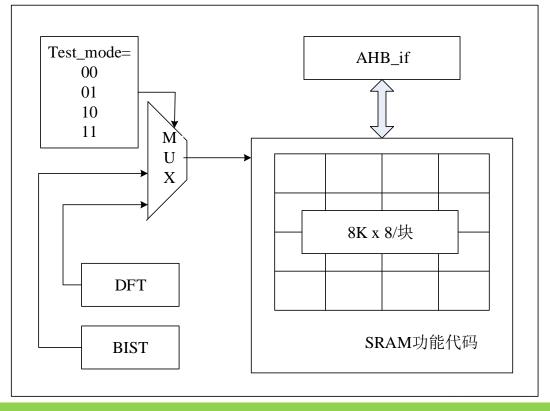
AHB-SRAMC 设计需求



- * 支持低功耗
- ❖ 支持单周期读写
- ❖能够根据AHB总线的读写宽度进行相应的SRAM位宽选择
- ❖能够支持DFT/BIST测试

Power (current units = mA)

Pin	Fast Process 1.98V, 0°C	Typical Process 1.8V, 25°C	Slow Process 1.62V, 125°C
AC Current ^{1,4}	3.722	3.395	3.118
Read AC Current ⁴	3.414	3.114	2.871
Write AC Current ⁴	4.030	3.675	3.365
Peak Current ⁴	135.983	96.699	54.009
Deselected Current ^{2,4}	1.030	0.919	0.817
Standby Current ³	0.004	0.003	0.018



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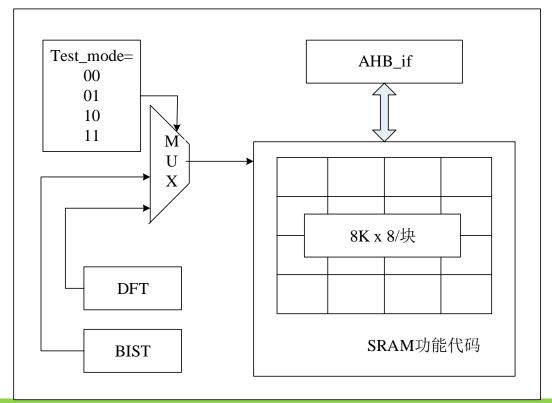
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AHB-SRAMC 设计规格



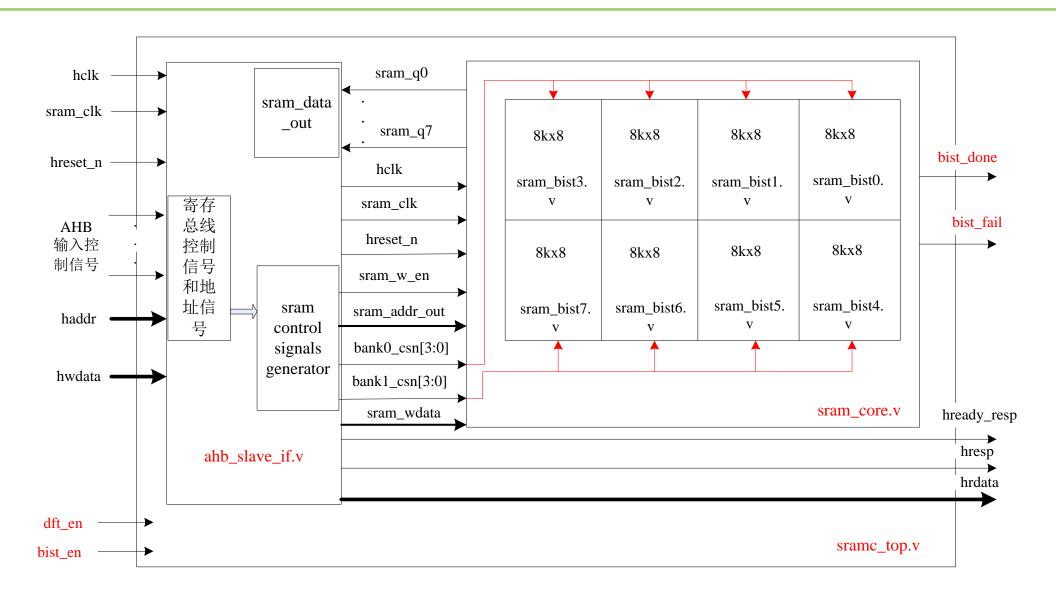
- ❖ 支持8位、16位和32位的SRAM数据读写操作
- ❖ 支持SRAM的单周期读写
- ❖ 支持在多块SRAM组成的存储器中,根据不同地址,系统选择一块或者多块 SRAM,未被选中的SRAM块则处在low power standby状态。
- ❖ 支持DFT/BIST功能





AHB-SRAMC 设计架构







AHB slave 接口



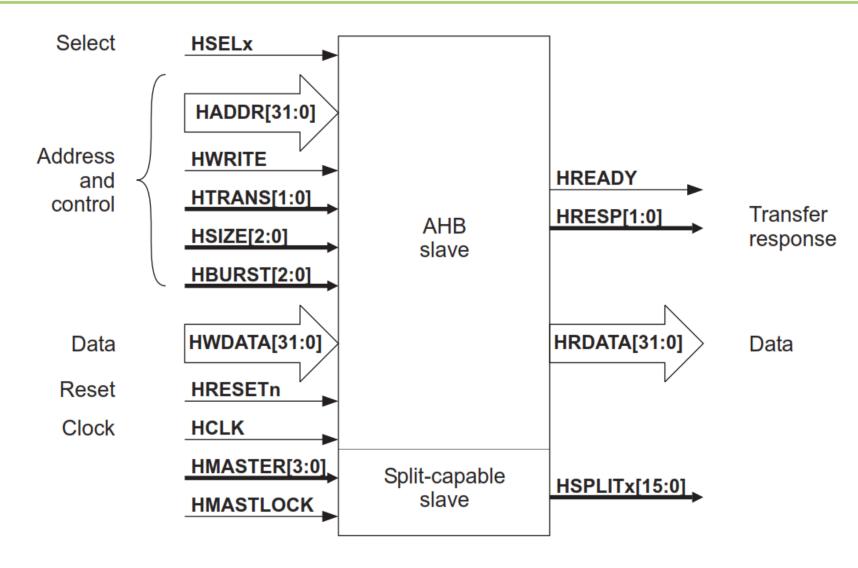
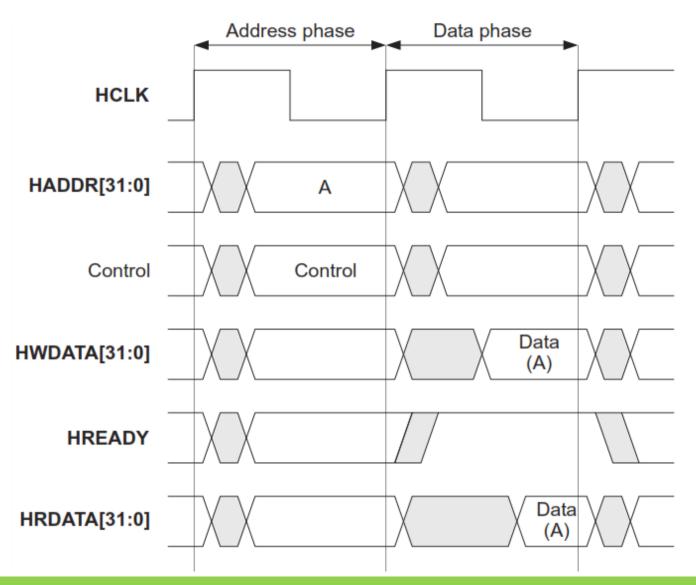




Figure 3-23 AHB bus slave interface

AHB 接口时序



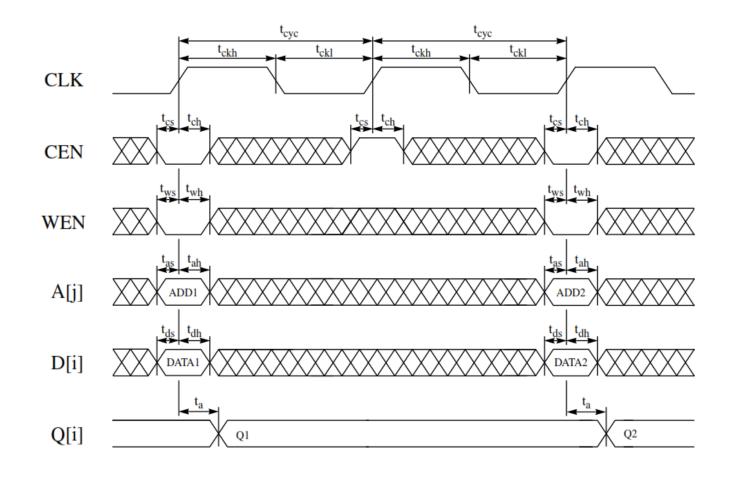




SRAM接口



Synchronous Single-Port SRAM Write-Cycle Timing







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